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Enhanced electrochemical performance of the MoS₂/Bi₂S₃ nanocomposite-based electrode material prepared by a hydrothermal method for supercapacitor applications

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Supercapacitors are widely used energy storage systems in the modern world due to their excellent electrochemical performance, fast charging capability, easy handling, and high power density. In the present work, pure MoS₂ and MoS₂/Bi₂S₃ nanocomposites with different compositions of bismuth were synthesized by the hydrothermal method. The structural properties of the electrode materials were studied using the XRD technique, which confirmed the formation of MoS₂ and the secondary phase of Bi₂S₃ while increasing Bi substitution. The morphological studies of the synthesized electrode materials were performed using SEM, TEM, and HRTEM techniques, which indicated the 3D layered hierarchical structure of MoS₂ nanospheres and the nanosheet-like structure of Bi₂S₃. The electrochemical properties of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites were analysed by CV, CP, and EIS techniques using a 2 M KOH electrolyte in a three-electrode system. The CV curves show evidence of significant improvement in the electrochemical performance of MoS₂/Bi₂S₃ composites compared to that of pure MoS₂. The calculated specific capacitances of MoS₂/Bi₂S₃ nanocomposites were relatively higher than those of pristine MoS₂. The 20 mol% Bi added sample showed a maximum specific capacitance of 371 F g⁻¹, compared to pristine MoS₂ and other samples at a current density of 1 A g⁻¹. The kinetics of the electrochemical process was studied. The Nyquist plots indicated that the Bi-added nanocomposites had lower *R*_{esr} and *R*_{CT} values, which resulted in high electrochemical performance. The experimental results revealed that Bi-substitution can further enhance the electrochemical energy storage performance of MoS₂ for supercapacitor applications.

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1. Introduction

Recent studies in nanotechnology have paved the way for designing and preparing various nanostructured materials. These materials have the potential to revolutionize numerous industries by offering improved performance, new functionality, and unprecedented control over material properties. Nanostructured materials will dominate future energy storage and conversion technology, particularly supercapacitors, Li-ion batteries, thermoelectrics, and photovoltaic applications.¹⁻⁴ The supercapacitor is remarkably used as energy storage devices

because of their capability to achieve high energy density than typical capacitors and high power density than Li-ion batteries. Typically, supercapacitors bridge the gap between conventional capacitors and batteries, which offers high capacitance, fast charging, slow discharging, more extended life cycles, high stability, superior performance at low temperatures, less weight, and cost-effectiveness. The storage capacity of supercapacitors is primarily determined by the surface area and pore structure of electrodes, which affects the available electrode-electrolyte interface for charge storage. Supercapacitors excel in applications requiring rapid energy transfer and high power output. The high self-discharge rate and lower energy density compared to batteries are the challenges in supercapacitors, which restrict their lower voltage applications.^{5,6}

Supercapacitors store energy through two behaviours, such as electric double-layer capacitance (EDLC) and pseudo capacitance. In EDLC supercapacitors, the electrode material stores the charges through electrostatic adsorption and desorption of electrolyte ions. At the surface of electrodes, there is no

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electrical charge transfer between electrodes and electrolytes.^{7,8} EDLC supercapacitors have high power density and good cyclic stability. Low-dimensional carbon-based materials such as graphene, carbon nanotubes, graphene oxides, and reduced graphene oxides have good EDLC behaviour.^{9–12} Pseudocapacitance is an electrochemical phenomenon where the existence of fast sequences of adsorption and intercalation charge transfers with reversible structural modifications resulted in high charge storage capacity. The fast electron charge transfer takes place due to a reversible oxidation and reduction reaction on the surface of the electrode and electrolyte interface, which produces a faradaic capacitive type current. Conducting polymers, metal oxides, and metal sulphides have delivered a profound pseudocapacitive behaviour.¹³ The specific capacitance of these electrochemical capacitors is 10–100 times greater than carbon-based electrode materials for supercapacitor applications.¹⁴

Various kinds of nanostructured electrode materials are employed in supercapacitor applications, wherein, two-dimensional layered materials have a large surface area, which allows maximum active sites on the surface, more flexibility, and high chemical and thermal stability. Hence, 2D materials are highly suitable as electrodes for electrochemical capacitors. Transition metal dichalcogenides (TMDs) have good catalytic and electrochemical performance because of their high conductivity among various 2D materials beyond graphene.^{15,16} The general formulas for TMDs are AB₂, where the term A refers to transition metals, and the term B refers to chalcogen elements such as sulphur, selenium, and tellurium. In the crystal structure of TMDs, the layers of transition metal atoms were sandwiched between the layers of chalcogen atoms.¹⁷ The majority of TMDs have the capacity to exist in more than one crystal structure, notably the semiconducting (2H) and semi-metal (1T) phases, and have physical and chemical properties that vary with thickness. Each layer in the TMD structures is weakly bonded to its neighbours by van der Waals forces, making physical or chemical isolation simple.¹⁸ MoS₂ belongs to the family of TMDs, which have a large surface area, rich redox peaks, good intrinsic properties, and high theoretical capacitance. These properties of MoS₂ make it suitable for energy storage applications such as supercapacitors.^{19–21} The monolayer MoS₂ has a direct band gap of 1.8 eV, and the bulk MoS₂ has an indirect band gap is about 1.2 eV. The layered structure of molybdenum disulfide is similar to graphene, which supports the fast moving of electrons in the redox reactions.^{22–25}

Bismuth materials are used in numerous applications such as gas sensors, catalysts, and energy storage systems because of their low cost, nontoxic properties, high conductivity, and dielectric behaviour. Bismuth-based nanocomposite materials having relatively good redox reactions in the negative potential window can be used as negative electrodes in energy storage systems.^{26,27} Bismuth compounds such as bismuth oxides and bismuth sulfides are n-type semiconductors having high refractive index, narrow energy band gap, and good electrochemical activities. The surface morphology, crystalline structure, size, shape, and dimensions of bismuth chalcogenides

have a significant impact on their electrochemical properties.²⁸ Due to the substantial intercalation space in their crystalline structure, bismuth chalcogenides are used in electrochemical energy storage devices; their lattice interlayer provides routes for the transit and employment of guest ions.²⁹ The inclusion of other molecules into MoS₂ nanosheets can increase the layer distance between each stacked layer, which impacts the electrochemical behaviour. The metal oxide and sulfide-based MoS₂ hybrid electrodes have enhanced electrochemical performance because of their high pseudocapacitance, which can store charge at a higher rate than a conventional electric double-layer capacitor.^{30,31}

A viable option is to combine a nanomaterial with metal sulfides in order to address the conductivity limitations of individual metal sulfides. This integration offers flexible platforms for effective charge transfer. MoS₂, Bi₂S₃, CuS, NiS, NiS₂, Ni₃S₂, CoS, CoS₂, CdS, SnS, and SnS₂ are all promising choices for supercapacitor electrodes due to their impressive electrochemical performances.^{32–36} S. Jia *et al.* developed a composite material NiCo-DHS, which exhibited a high specific capacity of 973.6C g⁻¹ and remains durable over 8000 cycles, with only a small capacity loss of 7.4%. It achieved an energy density of 65.91 W h kg⁻¹ and a power density of 0.89 kW kg⁻¹, demonstrating its considerable potential.³⁷ A nonaqueous sodium-ion hybrid energy storage device has been developed, which utilizes VS₂ nanosheets grown on electrochemically exfoliated graphene as the negative electrode and activated carbon as the positive electrode. These hybrid devices exhibited a high areal capacitance of 110.7 mF cm⁻² over a wide potential range of 0.01–3.5 V. Additionally, they demonstrated an impressive areal energy density of 188.3 μW h cm⁻² and excellent cycling stability, maintaining their performance for up to 5000 cycles without noticeable decay.³⁸ W. Zhang *et al.* developed a Ti₃C₂Tx/Bi₂S₃@N-C electrode that showed a specific capacitance of 653 F g⁻¹, which is significantly higher than other binary composites or similar MXene-based materials. The Zinc-ion hybrid capacitor consists of Ti₃C₂Tx/Bi₂S₃@N-C and Zn foil as electrodes, and it exhibits a high specific capacitance of 150.33 F g⁻¹, along with a maximum energy density of 46.98 W h kg⁻¹ at a power density of 750 W kg⁻¹.³⁹ Utilizing metal sulfides in supercapacitors offers numerous benefits, including high energy density, improved stability, enhanced conductivity, a wide range of materials, environmental advantages, compatibility with flexible devices, and potential for hybrid systems. This makes them an attractive choice for advancing the field of supercapacitor technology. However, only a few studies have been published so far, on the effects of Bi-substitution in MoS₂ for energy storage applications. Therefore, the main objective of the present work is to study the effects of Bi-substitution in MoS₂/Bi₂S₃ nanocomposite materials on their structural, morphological, and electrochemical performance.

2. Materials and methods

2.1. Materials

Sodium molybdate dehydrate (Sigma-Aldrich laboratory with 99.5% purity), thioacetamide (Alfa Aesar laboratory with 98%



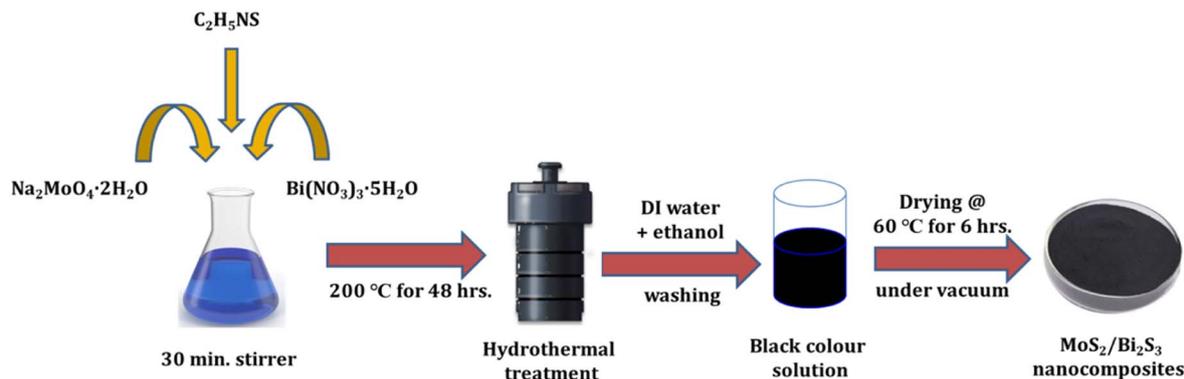


Fig. 1 Schematic representation of the hydrothermal synthesis of $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites.

purity), and bismuth nitrate (Alfa Aesar laboratory with 98% purity) were used as precursors. All chemicals and reagents were purchased as analytical grade and used without any further purification.

2.2. Hydrothermal synthesis of pure MoS_2

The hydrothermal method was used to synthesize pure MoS_2 nanoparticles. First, 0.05 M of sodium molybdate dihydrate ($\text{Na}_2\text{MoO}_4 \cdot 2\text{H}_2\text{O}$) and 0.1 M of thioacetamide ($\text{C}_2\text{H}_5\text{NS}$) were taken in the molar ratio of 1 : 2. The precursors were dissolved in 140 ml DI water and stirred for 30 minutes. Then, the solution was transferred into a 200 ml Teflon-lined stainless steel autoclave. After that, the autoclave was kept in the box furnace at 200 °C for 48 hours. The black precipitate was collected and washed several times using ethanol and deionized water. Finally, the sample was dried in a vacuum oven at 60 °C for 6 hours.

2.3. Hydrothermal synthesis of $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites

$\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites were synthesized using a hydrothermal method by adding Bi with different mol%. To synthesize 5 mol% Bi-added composite, 0.0475 M of sodium molybdate dihydrate, 0.1 M of thioacetamide, and 0.0025 M of bismuth nitrate were dissolved in 140 ml of DI water and further stirred for 30 minutes. The resultant solution was transferred to a Teflon-lined stainless steel autoclave and kept in a box furnace at 200 °C for 48 h. Finally, the black color precipitate was collected and washed out several times using ethanol and deionized water and then dried in a vacuum oven at 60 °C for 6 h. A similar procedure was followed to synthesize composites with different Bi concentrations of 5, 10, 15, and 20 mol% and the samples were named as MBS-1, MBS-2, MBS-3, and MBS-4, respectively. A schematic representation of the hydrothermal synthesis of $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites is shown in Fig. 1.

2.4. Characterization techniques

The morphology of pristine MoS_2 and $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites was analyzed using the TESCAN VEGA 3 Scanning electron microscope (SEM) and FEI TECHNAI G2 20 TWIN high-resolution transmission electron microscope (HRTEM). The

structural properties of the pristine MoS_2 and $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites were analyzed by XRD using a REGAKU SMARTLAB diffractometer. The XPS analysis of pristine MoS_2 and $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites was performed on a PHI Versaprobe III instrument. The electrochemical properties of pristine MoS_2 and $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites were studied by CP, CV, and EIS analysis using CH Instruments, USA (CHI6008E).

2.5. Electrochemical studies

The active electrode material, Super P® carbon black and polyvinylidene fluoride (PVDF) were taken in the weight ratio of 80 : 10 : 10 respectively, and well mixed using a mortar and pestle. The slurry was prepared from the above mixture with *N*-methylpyrrolidone (NMP) as a solvent. Super P® carbon black was used as a conductive additive and PVDF was used as a binder. The prepared slurry was coated on Ni foam over the area of 1 cm², which served as the working electrode in a three-cell electrode setup. The total weight of the slurry coated on one working electrode was 4 mg, and the areal mass loading of the active electrode material was 3 mg. A platinum wire and Ag/AgCl served as counter and reference electrodes, respectively. 2 M KOH was used as the electrolyte in the electrochemical studies of pristine MoS_2 and $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites. The electrochemical properties were analyzed using CH Instruments at room temperature. The cyclic voltammetry (CV), chronopotentiometry (CP), and electrochemical impedance spectroscopy (EIS) tests were carried out using a three-cell electrode configuration.

3. Results and discussion

3.1. Structural and morphological analysis

XRD patterns of pristine MoS_2 and $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites recorded in the 2θ range from 5–80° and shown in Fig. 2. The diffracted peaks of pristine MoS_2 indexed to the planes of (002), (100), and (106) well matched with the standard JCPDS data (card no. 37-1492).⁴⁰

The secondary phase of Bi_2S_3 was formed by increasing the Bi concentration in $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposites. The diffraction peak intensities of Bi_2S_3 were indexed to the planes of (200),



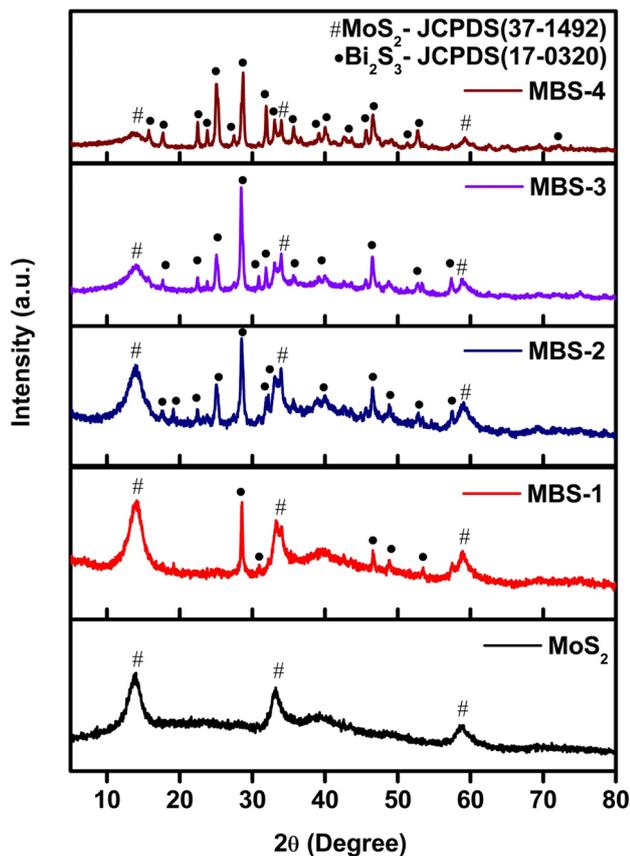


Fig. 2 XRD patterns of the pristine MoS₂, MBS-1, MBS-2, MBS-3, and MBS-4 samples.

(120), (220), (101), (310), (211), (221), (240), (430), (440), (501), (312), (360), and (811) were in good agreement with those from the standard JCPDS data (card no. 17-0320). The mixed phases of MoS₂ and Bi₂S₃ were clearly observed in the XRD patterns of MoS₂/Bi₂S₃ nanocomposites and no other diffraction peaks were observed in the XRD pattern. The secondary phase of Bi₂S₃ was more dominant at higher concentration of Bi in MoS₂/Bi₂S₃ nanocomposites.^{41–43}

Fig. 3(a) represents the SEM image of pristine MoS₂, formed as a 3D flower-like nanostructure. The close view of the pristine MoS₂ nanoparticles is shown in Fig. 3(b) with the size of 300–600 nm range. The 3D nanoflowers showed hierarchical structures with pores and clumsy sheets. The spherical structure was formed due to the agglomeration of more nanosheets together. The morphology of MoS₂/Bi₂S₃ nanocomposites with different concentrations of Bi is shown in Fig. 3(c–f), respectively. Bi₂S₃ was grown with MoS₂ while increasing the Bi concentration in the MoS₂/Bi₂S₃ nanocomposites and clearly observed in the SEM images. The spherical structure of MoS₂ was stacked over Bi₂S₃ nanoflakes in MoS₂/Bi₂S₃ nanocomposites.

The TEM and HRTEM were used to analyze the morphology and crystalline nature of the pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposite and the images are shown in Fig. 4(a–c). The agglomerations of nanosheets were observed and the lattice fringes were clearly observed in the HRTEM images. The

interplanar distance of 0.58 nm was calculated from the lattice fringes, which corresponds to the (002) plane of MoS₂ as observed from the XRD pattern. In Fig. 4(d), the rings corresponding to (002), (100), and (110) planes were observed in the SEAD pattern, which verified the structure of pure MoS₂ as hexagonal.^{44–46} Fig. 4(e–g) represents the TEM and HRTEM images of MBS-4 nanocomposite. It was clearly observed from the images that MoS₂ and Bi₂S₃ were stacked together. The interplanar spacings of 0.58 nm and 0.30 nm were observed, which corresponded to the (002) plane of MoS₂ and (211) plane of Bi₂S₃. The SAED pattern shows a clear ring with spots, which confirms the polycrystalline nature of the MBS-4 nanocomposite (Fig. 4(h)).⁴⁷

The EDAX spectra were recorded to investigate the composition of the synthesized pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposite samples. The chemical composition of pristine MoS₂ was confirmed and displayed in Fig. 5(a). Despite the peaks indicated, copper and carbon peaks were also noticed in the EDAX spectra of both samples, which may have originated from the grid. Fig. 5(b) represents the EDAX spectrum of the MBS-4 nanocomposite, in which the elements of Mo, Bi, and S were clearly observed. The EDAX spectrum confirms that no other elements were present in the sample, indicating that it was homogeneous in terms of its elemental composition.^{48,49}

3.2. X-ray photoelectron spectroscopy (XPS) analysis

X-ray photoelectron spectroscopy (XPS) was used to analyze the chemical composition and binding state of elements in the samples. The survey spectra of pure MoS₂ and MBS-4 samples confirmed the presence of Mo, Bi, S, and C elements as shown in Fig. 6(a) and (b). The elemental carbon appeared as a result of the carbon tape used to hold the samples.⁵⁰ Fig. 6(c) represents the core level XPS spectrum of a pristine MoS₂ sample for Mo 3d. The strong doublet peaks exist at 229.5 eV and 232.7 eV corresponding to Mo 3d_{5/2} and Mo 3d_{3/2}, respectively, and the mild peak at 226.8 eV belonged to S 2s. Fig. 6(d) shows the core level XPS spectrum of S 2p for pristine MoS₂ sample with two strong peaks appearing at 162.2 eV and 163.4 eV corresponding to S 2p_{3/2} and S 2p_{1/2}, respectively.⁵¹

Fig. 6(e) represents the core level XPS spectrum of Mo 3d peaks for the MBS-4 nanocomposite. The strong doublet exists at the energy levels of 229.1 eV and 232.3 eV corresponding to Mo 3d_{5/2} and Mo 3d_{3/2}, respectively. Moreover, one of the weaker peaks exists at 226.0 eV for S 2s, and the other is located at 235.8 eV corresponding to Mo 3d_{3/2}, which is attributed to the presence of the Mo 6⁺ oxidation state. Oxidation occurred due to the formation of Bi₂S₃, which created the lack of sulfur atoms to form MoS₂. Such oxidation in the nanocomposite enhances the electronic property of the electrode material and further develops more active sites with good photocatalytic behavior indicating that MoO₃ is formed in the Bi-substituted nanocomposites.^{52,53}

Fig. 6(f) represents the core level XPS spectrum of S 2p peaks for the MBS-4 nanocomposite. The strong doublet peaks appeared at the binding energy of 161.5 eV and 163.5 eV, which correspond to S 2p_{3/2} and S 2p_{1/2}, respectively. Fig. 6(g)



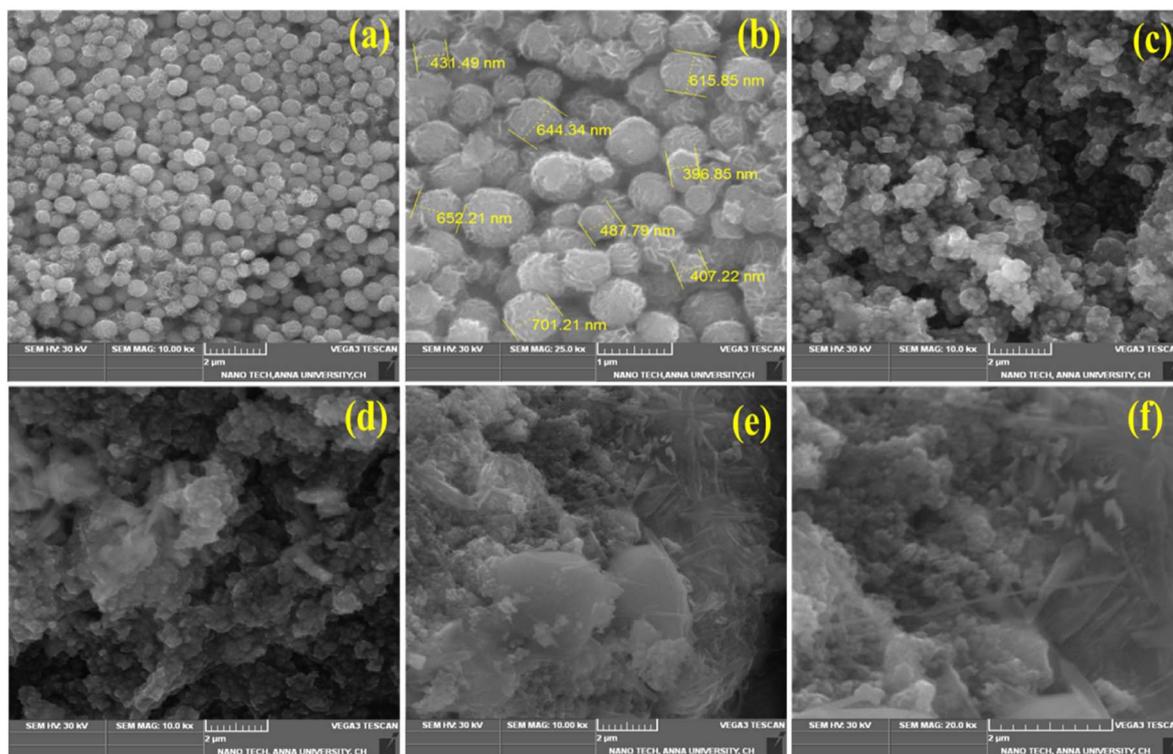


Fig. 3 (a and b) SEM images of the pristine MoS₂, (c–f) SEM images of MBS-1, MBS-2, MBS-3, and MBS-4 samples.

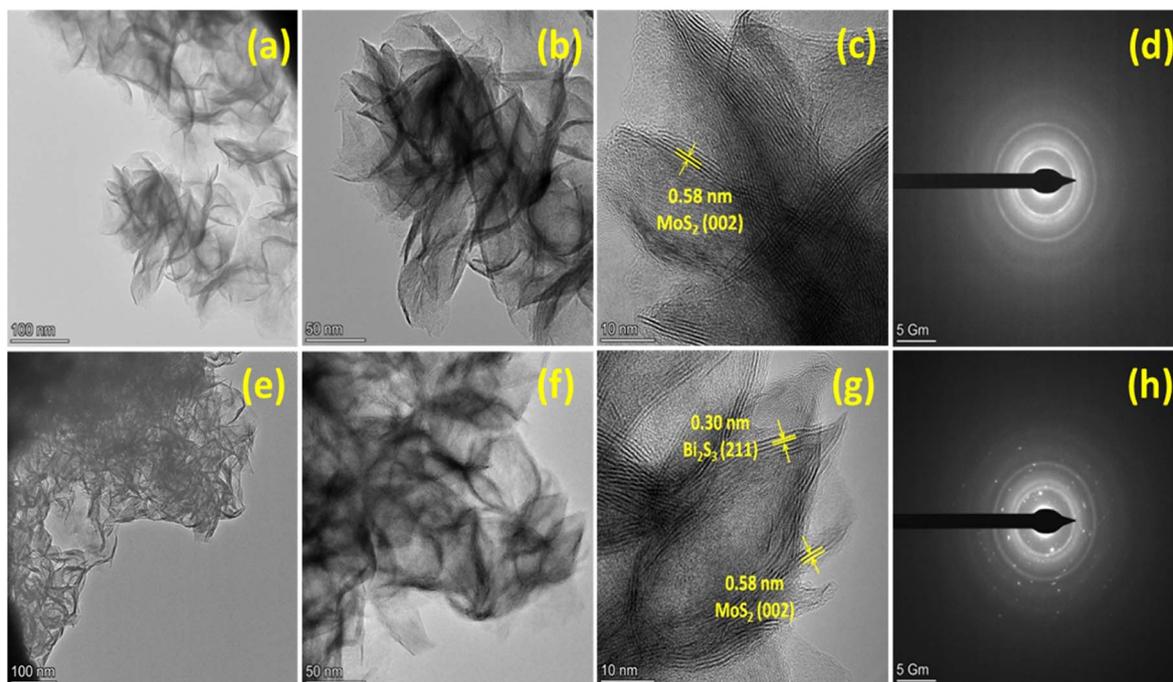


Fig. 4 (a–c) HRTEM images of MoS₂, (d) SAED pattern of MoS₂, (e–g) HRTEM images of MBS-4 nanocomposite, (h) SAED pattern of MBS-4 nanocomposite.

represents the core level XPS spectrum of Bi 4f peaks for the MBS-4 nanocomposite. The doublet peaks existed for Bi 4f_{7/2} at the binding energy of 158.2 eV and 159.2 eV, indicating the

presence of Bi₂O₃ in the composite.^{54,55} The peak corresponding to Bi 4f_{5/2} appeared at the binding energy of 164.8 eV. It is clearly noted that an energy gap of 5.6 eV existed between the two firm



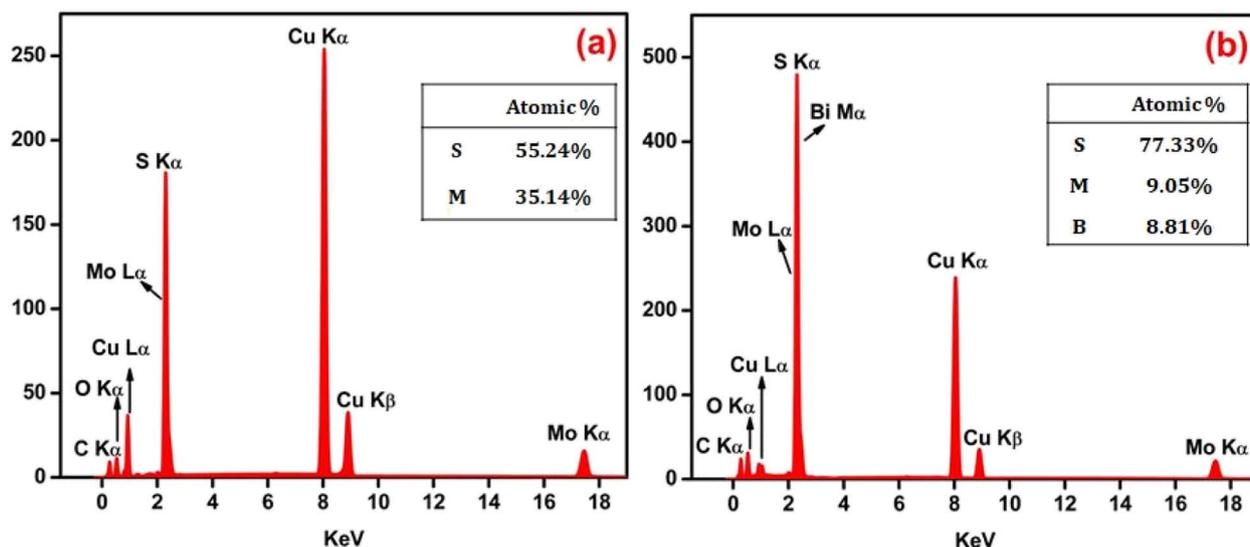


Fig. 5 (a and b) EDAX spectra of the pristine MoS₂ and MBS-4 nanocomposite.

peaks of Bi 4f_{7/2} and Bi 4f_{5/2}, indicating the formation of the Bi³⁺ state in the Bi₂S₃ phase.⁵⁶

3.3. Electrochemical analysis

Cyclic voltammetry analysis was used to study the oxidation and reduction reaction kinetics of the pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites. The response of the CV curve was significant in the potential window range from −1 to 0 V for all the scan rates from 5 to 100 mV s^{−1}. The specific capacitance of active materials can be calculated using the following eqn (1),⁵⁷

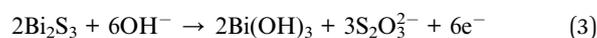
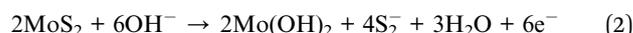
$$C_s = \frac{1}{m \times V_s \times \Delta V} \int_{V_1}^{V_2} I dv \quad (1)$$

where m is the mass of the active material (g), V_s is the scan rate of the electrode system (mV s^{−1}), and ΔV is the operating potential window (V).

Fig. 7(a–e) shows the CV curves of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at scan rates from 5 to 100 mV s^{−1}. Fig. 7(a) represents the CV response of pristine MoS₂. The redox peaks are clearly visible in the CV curve, indicating the pseudo-capacitive behavior due to a reversible surface redox reaction.⁵⁸ When the scan rate increases from 5 to 100 mV s^{−1}, the area of CV curves also increases and the shape of the curves remains symmetrical. It showed the ideal capacitive behavior of the pristine MoS₂. The maximum specific capacitance of pristine MoS₂ was 154 F g^{−1} at a scan rate of 5 mV s^{−1}. The CV curves of MoS₂/Bi₂S₃ nanocomposites showed relatively stronger redox peaks compared to those of the pristine MoS₂, indicating that the Bi-substitution increases the reversible faradaic redox reaction. Fig. 7(b) represents the CV response of the MBS-1 electrode, which exhibited a larger current flow than the pristine MoS₂. The formation of heterostructure between MoS₂ and Bi₂S₃ increases the conductivity and electrochemical properties of MoS₂/Bi₂S₃ nanocomposites. The highest specific capacitance for the MBS-1 electrode was 203 F g^{−1} at a scan rate of 5 mV s^{−1}. The current densities are maximum at higher scan

rates due to the rapid diffusion and absorption of ions at the electrode–electrolyte interface.

Fig. 7(c and d) represents the CV curves of MBS-2 and MBS-3 electrodes, respectively. The electrochemical properties of the composites gradually increased with Bi-substitution, as shown in the CV curves. The CV response of the MBS-4 electrode is shown in Fig. 7(e). The two strong oxidation peaks are clearly visible at low scan rates, which correspond to the multiple oxidation states of the elements Mo and Bi. The presence of multiple oxidation states increases the electrochemical redox reactions and conductivity of MBS-4 nanocomposite electrodes. The highest specific capacitance of 425 F g^{−1} was obtained for Mo_{0.8}Bi_{0.2}S₂ nanocomposite at a 5 mV s^{−1} scan rate. Fig. 7(f) shows the CV comparison of the pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at a scan rate of 5 mV s^{−1}. The MBS-4 nanocomposite has a higher integrated CV area, indicating that more ion diffusion and absorption occur at the electrode/electrolyte interface. It has a strong reduction peak at −0.6 V and two oxidation peaks at −0.42 V and −0.3 V. Fig. 7(g) shows variations in the specific capacitance of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at different scan rates. The MBS-4 sample had the highest specific capacitance than other composites and pristine MoS₂. The specific capacitances of the pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites were higher at a scan rate of 5 mV s^{−1}. At higher scan rates, the ions present in the electrolytes move very fast, which cannot access all the active sites of the electrode surface. This attributes low specific capacitance at higher scan rates.^{59,60} The redox reactions of a MoS₂/Bi₂S₃ composite electrode in the KOH electrolyte can be described as follows:



In the present work, the ions present in the electrolytes strongly interacted with the active sites of MoS₂ and Bi₂S₃ in the MoS₂/



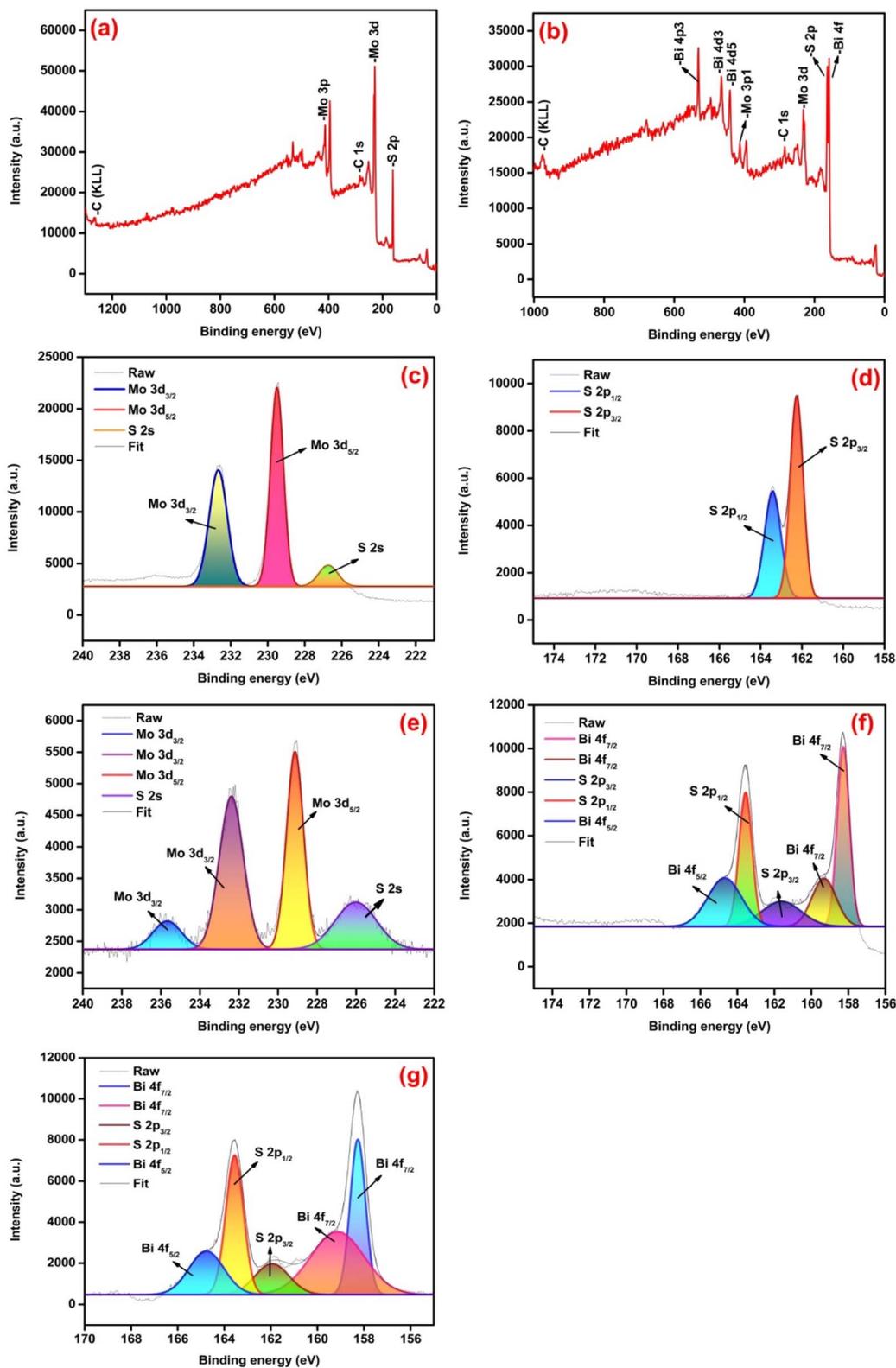


Fig. 6 (a and b) Survey spectrum of pristine MoS_2 and $\text{MoS}_2/\text{Bi}_2\text{S}_3$ nanocomposite, (c and d) XPS spectra of pristine MoS_2 for Mo 3d and S 2p respectively, (e–g) XPS spectra of MBS-4 nanocomposite for Mo 3d, S 2p and Bi 4f, respectively.



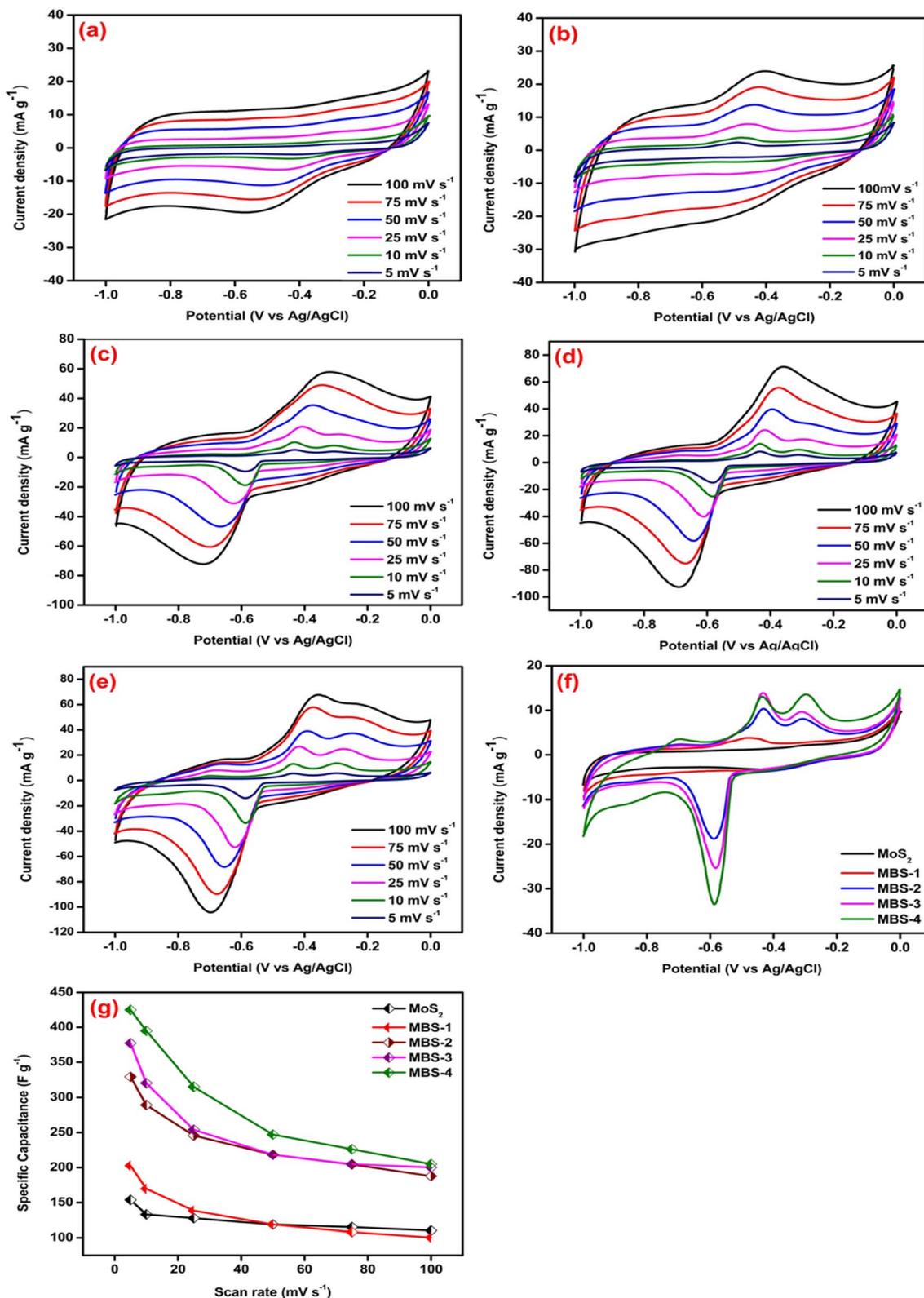


Fig. 7 (a–e) Cyclic voltammetry curves of pristine MoS₂, MBS-1, MBS-2, MBS-3, and MBS-4 electrodes, respectively (f) comparison of CV curves of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at a scan rate of 5 mV s⁻¹, (g) specific capacitances of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at various scan rates by cyclic voltammetry analysis.

Table 1 The specific capacitances of the pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at different scan rates by cyclic voltammetry analysis

Sample	Specific capacitance (F g ⁻¹) at different scan rates					
	100 mV s ⁻¹	75 mV s ⁻¹	50 mV s ⁻¹	25 mV s ⁻¹	10 mV s ⁻¹	5 mV s ⁻¹
MoS ₂	110	115	119	128	133	154
MBS-1	100	108	119	139	170	203
MBS-2	188	204	218	246	289	329
MBS-3	200	205	218	254	320	377
MBS-4	205	226	247	315	395	425

Bi₂S₃ nanocomposite electrodes. Hence, at low scan rates, MoS₂/Bi₂S₃ nanocomposites possess higher specific capacitance. The specific capacitances of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites were calculated at different scan rates using eqn (1) and are listed in Table 1.

Studying the various kinetic responses through electrochemical analysis enhances the comprehension of the charge/discharge process, and offers valuable insights for pinpointing and developing superior electrode materials for advanced

energy storage devices. The capacitive distribution can be approximated using the power law relationship between the current (*i*) and sweep rates (*v*), as shown in eqn (4). This can be performed by determining the *b*-value from the linear slope of the logarithm of *i* versus the logarithm of *v*.

$$i = av^b \quad (4)$$

The *b* value has practical applications in designing high-performance electrode materials. It can be used to differentiate between pseudocapacitive and battery-type materials and provide information about electrochemical reactions and charge storage mechanisms in different ion intercalation batteries. In accordance with the existing literature, the *b*-value is characterized by two predetermined values, specifically 0.5 and 1.0, which are indicative of two distinct conditions: diffusion control and capacitive response, respectively. The range of *b* values between 0.5 and 1.0 represents the “transition” area between capacitive materials (*b* = 1.0) and typical battery-type materials (*b* = 0.5).^{61–63} Fig. 8(a) shows the *b* values of MoS₂ and MoS₂/Bi₂S₃ composites. The value of *b* ~ 0.8 indicates the capacitive behavior of the pure samples. While increasing the Bi

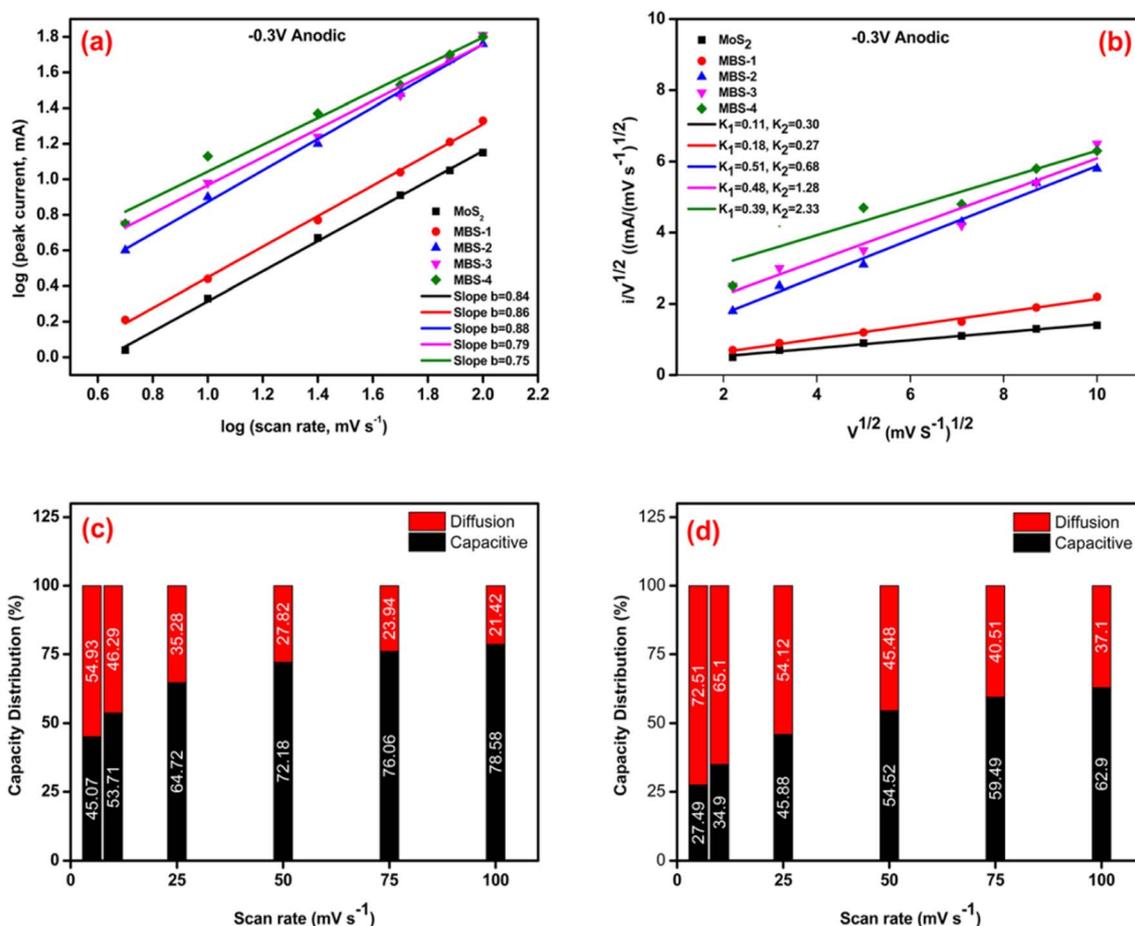


Fig. 8 (a–d) Capacitive charge storage distribution calculation, (a) power law ($i = av^b$) dependence of current on sweep rate for MoS₂ and MoS₂/Bi₂S₃ composites, (b) response of $v^{1/2}$ vs. $i/v^{1/2}$ (c) comparison of the capacitive and diffusion capacities distribution for MoS₂ electrode, (d) comparison of the capacitive and diffusion capacities distribution for MBS-4 electrode.



concentration is likely favorable with the diffusion of Mo and Bi ions.

J. Wang *et al.* developed a successful approach for analyzing and evaluating the contributions of capacitive and diffusion-controlled processes in the overall current.⁶⁴ By utilizing their calculation method, it became possible to separate and quantify the surface capacitive and diffusion-controlled effects in the current response, as expressed in eqn (5) provided.

$$i(v) = k_1v + k_2v^{1/2} = i_{\text{capacitive}} + i_{\text{diffusion}} \quad (5)$$

The equation can be transformed into a simpler form known as a first-order equation.

$$i(v)/v^{1/2} = k_1v^{1/2} + k_2 \quad (6)$$

By plotting the square root of the relationship between the sweep rate and currents, one can find the values of k_1 and k_2 based on the slope and y-axis intercept. The k_1 and k_2 values are estimated from Fig. 8(b). The capacity distribution of MoS₂ and MBS-4 electrodes are shown in Fig. 8c and d, respectively. MoS₂ showed 45%, 53%, 64%, 72%, 76%, and 78% capacitive distributions at the scan rates of 5, 10, 25, 50, 75, and 100 mV s⁻¹, respectively. The diffusion current was more at the higher concentration of Bi in the MoS₂/Bi₂S₃ composite. The MBS-4 electrode showed 27%, 34%, 45%, 54%, 59%, and 62% capacitive distributions at the scan rates of 5, 10, 25, 50, 75, and 100 mV s⁻¹, respectively.

The charge-discharge kinetics of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites were analyzed using chronopotentiometry. Fig. 9(a–e) shows CP curves of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at a constant potential window from -1 to 0 V. CP analysis was performed at various current densities from 1 to 5 A g⁻¹. The sample discharge time is one of the essential key factors for estimating the specific capacitance of the working electrodes. The specific capacitance of the sample was calculated using the following eqn (7).⁶⁵

$$C_s = \frac{I \times \Delta t}{m \times \Delta V} \quad (7)$$

where m is the mass of the active material (g), ΔV is the stable operating potential window (V), I is the current density (A), and Δt is the discharge time (s).

Fig. 9(a) represents the charge-discharge characteristics of pure MoS₂. The CP curves of pure MoS₂ are linear and well-symmetrical in shape. The maximum specific capacitance of pure MoS₂ is 261 F g⁻¹ at a current density of 1 A g⁻¹. The CP curves of the MBS-1 electrode are shown in Fig. 9(b). The variations in terms of charging-discharging time are clearly observed in MoS₂/Bi₂S₃ nanocomposite electrodes compared to those in pristine MoS₂. The bismuth substitution increases the reversible charging-discharging performance and it was clearly observed in the CP curves of MBS-2 and MBS-3 electrodes, as shown in Fig. 9(c and d). The specific capacitances are notably increased, indicating more interaction between the active sites of the electrode and electrolytes.

Fig. 9(e) represents the CP curves of the MBS-4 electrode. The remarkable variations are noted in the charging-discharging

time of the electrode. The highest specific capacitance of 371 F g⁻¹ was calculated at a current density of 1 A g⁻¹ among the other electrodes. The comparison between pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposite electrodes at a current density of 1 A g⁻¹ is shown in Fig. 9(f). The electrochemical activities are higher for the MoS₂/Bi₂S₃ composite electrode than the pristine MoS₂. For comparison, the specific capacitances of all electrodes were calculated from the discharge time of CP at a current density of 1 A g⁻¹, and the data are shown in Fig. 9(g). The specific capacitances of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites were calculated at different current densities using eqn (7) and are listed in Table 2. The calculated specific capacitances were high at lower current densities, which indicates that the diffusion of OH⁻ ions was high at low scan rates/current densities, in which the electrolytes have sufficient time to pass through the internal active sites of the electrode materials. At higher current densities and scan rates, the absorption of electrolyte ions took place at the surface of the electrode materials, which led to a less electrode/electrolyte interface and a lower specific capacitance.^{66,67}

The Ragone plot is a useful tool for assessing the performance of electrode materials in supercapacitors. It allows for the evaluation of energy density (E_d , measured in W h kg⁻¹) and power density (P_d , measured in kW kg⁻¹) using the following equations.⁶⁸

$$E_d = 0.5CV^2/3.6 \quad (8)$$

$$P_d = E \times 3600/\Delta t \quad (9)$$

where C is the specific capacitance of the electrode (F g⁻¹), V is the potential change during the discharge process after the internal resistance drop (v) and Δt is the discharge time of the electrode (s). The specific energy and power density of pristine MoS₂ and MoS₂/Bi₂S₃ composite electrodes are shown in Fig. 10.

It was observed that the energy density of the pristine MoS₂ increases from 13 W h kg⁻¹ to 26 W h kg⁻¹ at the power densities from 2500 W kg⁻¹ to 500 W kg⁻¹. Comparatively, the MBS-4 composite electrode shows a higher energy density of 52 W h kg⁻¹ at a power density of 500 W kg⁻¹ and remained 25 W h kg⁻¹ at 2500 W kg⁻¹. The results illustrated that the increase in the Bi concentration in MoS₂/Bi₂S₃ enhanced the energy density with high power output.

3.4. Electrochemical impedance spectroscopy (EIS) analysis

Electrochemical impedance spectroscopy analysis was performed to measure the electrical impedance at the interface between the working electrode and the electrolyte over a wide range of frequencies. Fig. 11 shows the electrical impedance spectra for pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposite electrodes. It can be observed that a very small semicircle can be observed in the high-frequency range, indicating the low charge transfer resistance between the working electrode and the electrolytes.⁶⁹ In the low-frequency region, the impedance spectrum was linear, confirming the ideal capacitive behaviour of the pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites. This indicates a low diffusion resistance between the ions in the



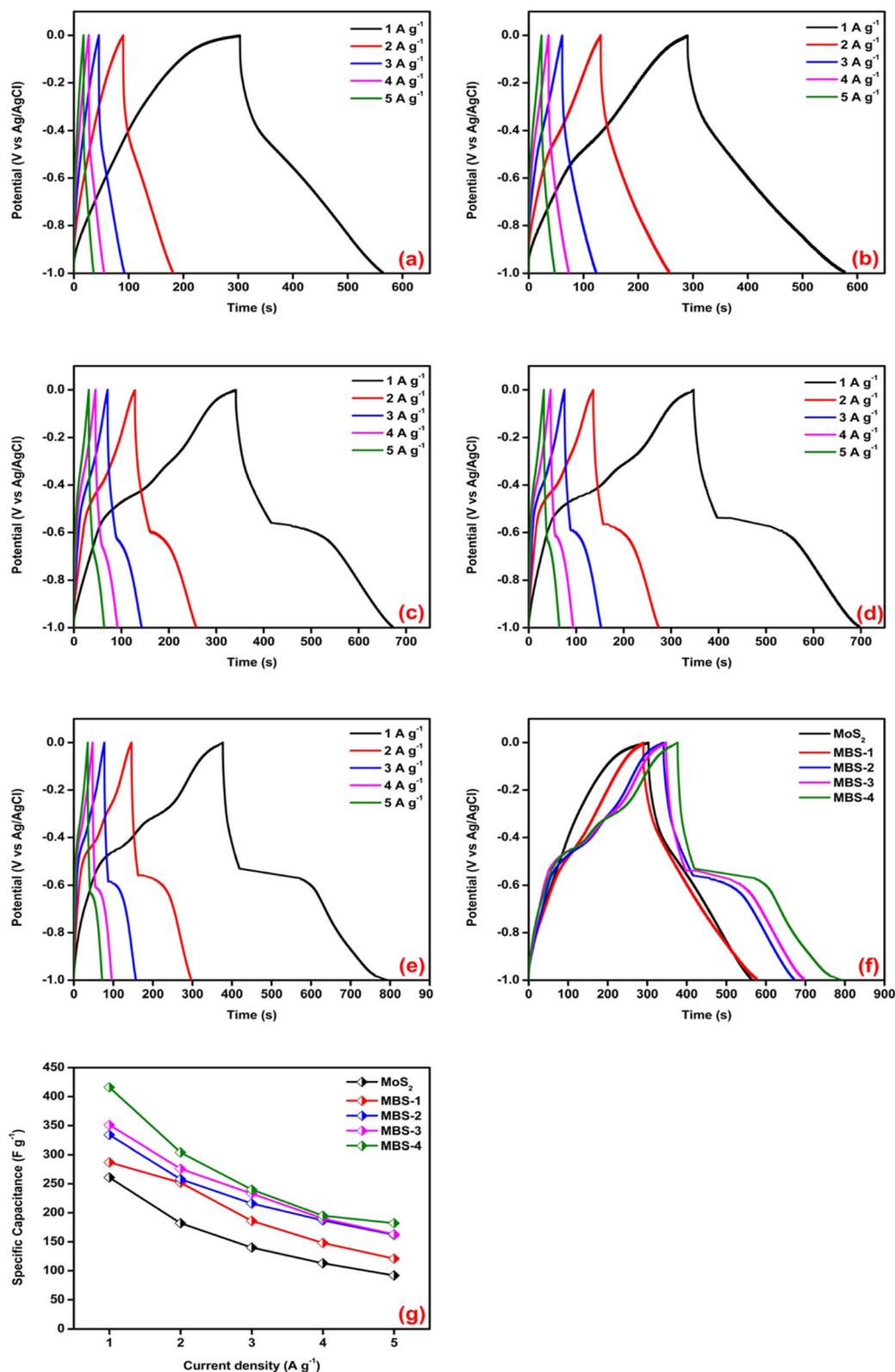


Fig. 9 (a–e) Charge–discharge characteristics of pristine MoS₂, MBS-1, MBS-2, MBS-3, and MBS-4 nanocomposites, respectively, (f) comparison of charge–discharge characteristics of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at a current density of 1 A g⁻¹, (g) specific capacitances of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at various current densities by charge–discharge analysis.



Table 2 The specific capacitances of the pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites at various current densities by chronopotentiometry analysis

Sample	Specific capacitance (F g ⁻¹) at different current densities				
	1 A g ⁻¹	2 A g ⁻¹	3 A g ⁻¹	4 A g ⁻¹	5 A g ⁻¹
MoS ₂	261	182	140	113	92
MBS-1	287	252	186	148	121
MBS-2	334	258	216	187	162
MBS-3	351	276	233	190	163
MBS-4	371	304	240	195	182

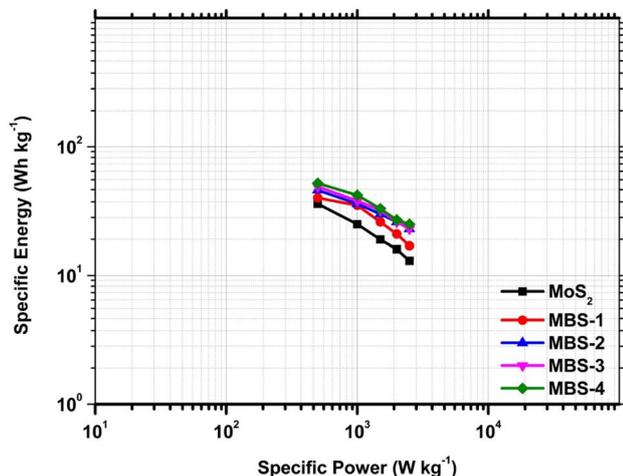


Fig. 10 Ragone plot of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites.

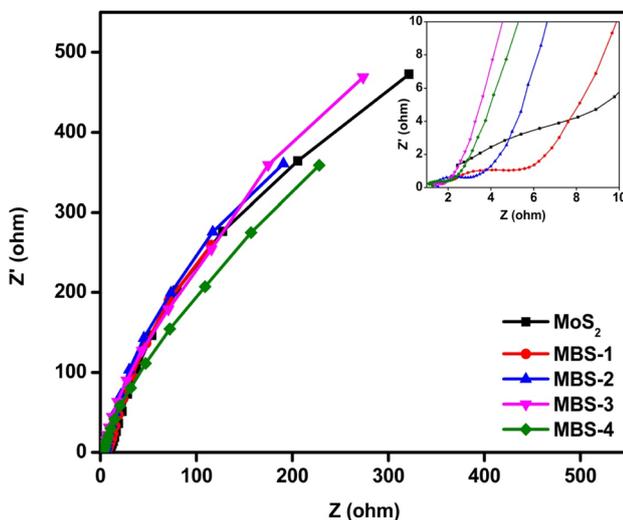


Fig. 11 Nyquist plot of pristine MoS₂ and MoS₂/Bi₂S₃ nanocomposites.

electrolytes and the working electrodes. The equivalence series resistance (R_{esr}) was measured at the intersection of the data with the x -axis. The R_{esr} of pristine MoS₂ was 2.4 ohms, which was significantly higher than that of MoS₂/Bi₂S₃ nanocomposite

electrodes. The addition of Bi increases the interfacial area between the electrode and the electrolyte and reduces the series resistance, which promoted charge transport. The MBS-4 electrode had the lowest R_{esr} among the other MoS₂/Bi₂S₃ nanocomposites. The observed series resistances of MBS-1, MBS-2, MBS-3, and MBS-4 electrodes are 2.2, 1.5, 1.3, and 1.2 ohms, respectively.

4. Conclusion

Pure MoS₂ and MoS₂/Bi₂S₃ nanocomposites with different Bi-concentrations were successfully synthesized using the hydrothermal method. The XRD patterns showed the formation of MoS₂ and Bi₂S₃ phases and the data well matched the standard JCPDS cards. The morphology of synthesized electrode materials was studied using SEM, TEM, and HRTEM analysis. The EDX analysis confirmed the presence of Mo, Bi, and S elements in the synthesized samples and the XPS analysis confirmed the oxidation states of pure MoS₂ and MoS₂/Bi₂S₃ nanocomposites. The electrochemical properties of MoS₂/Bi₂S₃ nanocomposites were studied using CV, CP, and EIS analysis. MoS₂/Bi₂S₃ nanocomposites showed excellent electrochemical properties with improved electrode/electrolyte interfaces compared to pristine MoS₂. The calculated specific capacitances of the pristine MoS₂, MBS-1, MBS-2, MBS-3, and MBS-4 composites were 154 F g⁻¹, 203 F g⁻¹, 329 F g⁻¹, 377 F g⁻¹, and 425 F g⁻¹ at 5 mV s⁻¹, respectively. Electrochemical measurements indicated that the MBS-4 electrode exhibited a higher energy density of 52 W h kg⁻¹ than the pristine MoS₂ electrode (26 W h kg⁻¹). The experimental findings suggested that MoS₂/Bi₂S₃ composites showed great potential as high-performance electrode materials in supercapacitors and other energy storage devices.

Conflicts of interest

The authors declare that they have no conflicts of interest.

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